

Supplementary Materials

Effect of non-intrinsic factors on pulse discharge and energy releasing performance of dielectric ceramics

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As show the Table S1, the test equipment type, samples size and resistance are different in different paper. And even, the mostly information is missing in several papers.

Table S1. Charge-discharge condition and $t_{0.9}$ of recently developed energy storage ceramics

Ref	Composition	Equipment type	Samples Size	Over-damped resistance(Ω)	P_{max}	$W_{dis-max}$	$t_{0.9}$
¹	(1-x)SrTiO ₃ -x(0.93Bi _{0.5} Na _{0.5} TiO ₃ -0.07Ba _{0.94} Sm _{0.04} Zr _{0.02} Ti _{0.98} O ₃)	CPR1701-100, PloyK, USA	none	1000	none	1.1J/cm ³ (150kV/cm)	0.18μs
²	(1-x)(0.75Na _{0.5} Bi _{0.5} TiO ₃ -0.25SrTiO ₃)-xAg(Nb _{0.85} Ta _{0.15})O ₃	Self-built	none	628.5	none	0.16J/cm ³ (10kV/cm)	340ns
³	(1-x)(0.65Bi _{0.5} Na _{0.5} TiO ₃ -0.35Bi _{0.1} Sr _{0.8} TiO ₃)-x(K _{0.5} Na _{0.5} NbO ₃)	Self-built	none	208	none	1.21J/cm ³ (120MV/m)	1.01μs

⁴	(1-x)(0.6Bi _{0.5} Na _{0.5} TiO ₃ -0.4Sr _{0.7} Bi _{0.2} TiO ₃)-xAgNbO ₃	Tongguo instruments technology, CFD-001	Thickness: 0.2mm Diameter: 2mm	300	none	1.50J/cm ³ (120kV/cm)	194ns
⁵	0.9(Sr _{0.7} Bi _{0.2})TiO ₃ -0.1Bi(Mg _{0.5} Me _{0.5})O ₃ (Me = Ti, Zr, and Hf)	CRP1701, PolyK	none	2000	none	1.0J/cm ³ (160kV/cm)	1.25μs
⁶	0.95SBKT-0.05NN	none	none	102	54.1MW/cm ³	2.1J/cm ³ (20kV/cm)	0.33μs
⁷	0.98(BNT-ST)-0.02 BaBi ₂ Nb ₂ O ₉	Tongguo instruments technology, CFD-001	none	200	30.57MW/cm ³	0.72J/cm ³ (120kV/cm)	0.3μs
⁸	0.9BaTiO ₃ -0.1(Bi _{0.9} Na _{0.1})(In _{0.8} Zr _{0.2})O ₃	none	none	270	none	0.46J/cm ³ (100kV/cm)	0.19μs
This work	0.55Bi _{0.5} Na _{0.5} TiO ₃ -0.45Ba _{0.85} Ca _{0.15} Ti _{0.85} Zr _{0.1} Sn _{0.05} O ₃	Tongguo instruments technology, CFD-003	Thickness: 0.3mm Diameter: 4mm	100	17.5MW/cm ³	0.23J/cm ³ (100kV/cm)	143ns

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